

**1 470 TO 1 610 nm FOR 2.5 Gb/s, CWDM  
InGaAsP MQW-DFB LASER DIODE****DESCRIPTION**

The NX6508 Series is a 1 470 to 1 610 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD. These devices are ideal for 2.5 Gb/s CWDM application.

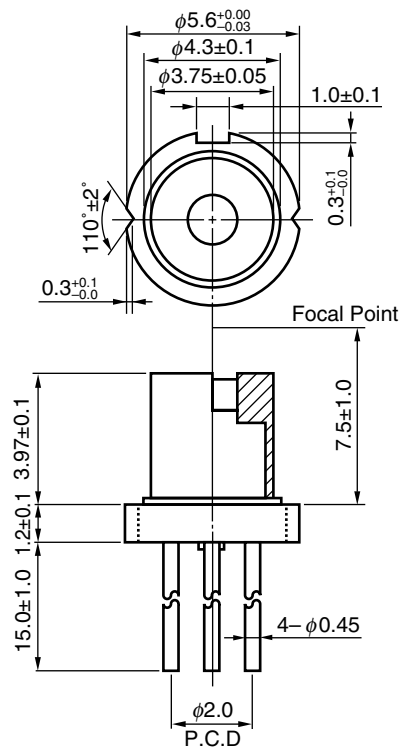
**FEATURES**

- |                                    |  |
|------------------------------------|--|
| • Optical output power             | $P_o = 5.0 \text{ mW}$   |
| • Peak emission wavelength         | $\lambda_p = 1\,470 \text{ to } 1\,610 \text{ nm}$ (Based on CWDM) |
| • Low threshold current            | $I_{th} = 10 \text{ mA}$   |
| • High speed                       | $t_r = 100 \text{ ps MAX.}$<br>$t_f = 150 \text{ ps MAX.}$         |
| • Side mode suppression ratio      | SMSR = 40 dB   |
| • Operating case temperature range | $T_c = -20 \text{ to } +85^\circ\text{C}$                          |
| • InGaAs monitor PIN-PD            |  |
| • CAN package                      | $\phi 5.6 \text{ mm}$  |
| • Based on Telcordia reliability   |  |

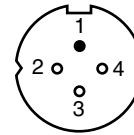


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### PACKAGE DIMENSIONS (UNIT: mm)

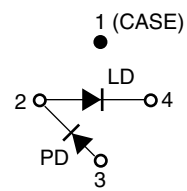


**BOTTOM VIEW**

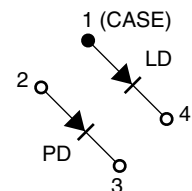


## PIN CONNECTIONS

**NX6508GHxx<sup>\*1</sup>**



NX6508GKxx\*1



\*1 Please refer to **ORDERING INFORMATION**.

# ORDERING INFORMATION

NX6508 □□xx

Wavelength code : Refer to **Table A**

Package code : Refer to **PACKAGE DIMENSIONS**

# ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power	P <sub>o</sub>	10	mW
Forward Current of LD	I <sub>F</sub>	150	mA
Reverse Voltage of LD	V <sub>R</sub>	2.0	V
Forward Current of PD	I <sub>F</sub>	2.0	mA
Reverse Voltage of PD	V <sub>R</sub>	15	V
Operating Case Temperature	T <sub>C</sub>	−20 to +85	°C
Storage Temperature	T <sub>stg</sub>	−40 to +85	°C
Lead Soldering Temperature	T <sub>sld</sub>	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

**ELECTRO-OPTICAL CHARACTERISTICS (T<sub>c</sub> = -20 to +85°C, unless otherwise specified)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Optical Output Power	P <sub>o</sub>	CW		5.0		mW
Operating Voltage	V <sub>op</sub>	P <sub>o</sub> = 5.0 mW		1.1	1.6	V
Threshold Current	I <sub>th</sub>	T <sub>c</sub> = 25°C		10	20	mA
					50	
Differential Efficiency	η <sub>d</sub>	P <sub>o</sub> = 5.0 mW, T <sub>c</sub> = 25°C	0.15	0.25		W/A
		P <sub>o</sub> = 5.0 mW	0.08			
Temperature Dependence of Differential Efficiency	Δη <sub>d</sub>	Δη <sub>d</sub> = 10 log $\frac{\eta_d (@ T_c^\circ\text{C})}{\eta_d (@ 25^\circ\text{C})}$	-3.0	-1.6		dB
Peak Emission Wavelength	λ <sub>p</sub>	P <sub>o</sub> = 5.0 mW, T <sub>c</sub> = 35°C	λ <sub>p</sub> -2	λ <sub>p</sub> +1	λ <sub>p</sub> +2	nm
Temperature Dependence of Peak Emission Wavelength	Δλ/ΔT	CW	0.08	0.1	0.12	nm/°C
Side Mode Suppression Ratio	SMSR	P <sub>o</sub> = 5.0 mW	30	40		dB
Rise Time	t <sub>r</sub>	20-80%, P <sub>o</sub> = 5.0 mW			100	ps
Fall Time	t <sub>f</sub>	80-20%, P <sub>o</sub> = 5.0 mW			150	ps
Monitor Current	I <sub>m</sub>	V <sub>R</sub> = 1.5 V, P <sub>o</sub> = 5.0 mW	200	1 000	2 000	μA
Monitor Dark Current	I <sub>D</sub>	V <sub>R</sub> = 1.5 V, T <sub>c</sub> = 25°C		0.1	10	nA
		V <sub>R</sub> = 1.5 V		10	100	

\*1 CWDM Wavelengths

λ<sub>p</sub> = 1 470, 1 490, 1 510, 1 530, 1 550, 1 570, 1 590, 1 610 nm

Please refer to **Table A**.

**Table A: CWDM wavelength code (@ T<sub>c</sub> = 35°C)**

Wavelength Code	MIN. (nm)	TYP. (nm)	MAX. (nm)
47	1 468	1 470	1 472
49	1 488	1 490	1 492
51	1 508	1 510	1 512
53	1 528	1 530	1 532
55	1 548	1 550	1 552
57	1 568	1 570	1 572
59	1 588	1 590	1 592
61	1 608	1 610	1 612

**REFERENCE**

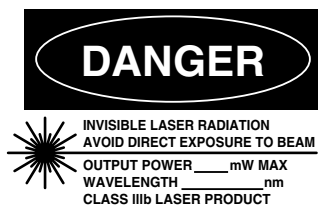
Document Name	Document No.
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PL10161E
Opto-Electronics Devices Pamphlet	PX10160E

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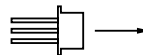
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M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible  
Laser Radiation is emitted from  
this aperture

<b>Warning</b>	Laser Beam	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> <li>• Do not look directly into the laser beam.</li> <li>• Avoid exposure to the laser beam, any reflected or collimated beam.</li> </ul>
<b>Caution</b>	GaAs Products	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> <li>• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.                             <ol style="list-style-type: none"> <li>1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> <li>2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li> </ol> </li> <li>• Do not burn, destroy, cut, crush, or chemically dissolve the product.</li> <li>• Do not lick the product or in any way allow it to enter the mouth.</li> </ul>

► For further information, please contact

**NEC Compound Semiconductor Devices, Ltd.** <http://www.ncsd.necel.com/>

E-mail: [salesinfo@ml.ncsd.necel.com](mailto:salesinfo@ml.ncsd.necel.com) (sales and general)

[techinfo@ml.ncsd.necel.com](mailto:techinfo@ml.ncsd.necel.com) (technical)

Sales Division TEL: +81-44-435-1573 FAX: +81-44-435-1579

**NEC Compound Semiconductor Devices Hong Kong Limited**

E-mail: [ncsd-hk@elhk.nec.com.hk](mailto:ncsd-hk@elhk.nec.com.hk) (sales, technical and general)

Hong Kong Head Office TEL: +852-3107-7303 FAX: +852-3107-7309

Taipei Branch Office TEL: +886-2-8712-0478 FAX: +886-2-2545-3859

Korea Branch Office TEL: +82-2-558-2120 FAX: +82-2-558-5209

**NEC Electronics (Europe) GmbH** <http://www.ee.nec.de/>

TEL: +49-211-6503-0 FAX: +49-211-6503-1327

**California Eastern Laboratories, Inc.** <http://www.cel.com/>

TEL: +1-408-988-3500 FAX: +1-408-988-0279